Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-597-1327
Inclosure Material:
Glass
Overall Length:
Between 0.200 inches and 0.225 inches
Overall Height:
Between 0.137 inches and 0.148 inches
Overall Width:
Between 0.137 inches and 0.148 inches
End Application:
E-3 block 404
Mounting Method:
Press fit
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
100.0 reverse voltage, peak
Current Rating Per Characteristic:
125.00 amperes peak forward surge current
Product Name:
Mil spec: semiconductor device, diode, silicon, ultrafast recovery, power rectifier, type jantx1n5809us
Terminal Type And Quantity:
2 bonding pad
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0
Mil-std (military Standard):
spec.